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**Vishay Semiconductors** 

## Thyristor High Voltage, Phase Control SCR, 40 A



PRIMARY CHARACTERISTICS						
I <sub>T(AV)</sub> 35 A						
V <sub>DRM</sub> /V <sub>RRM</sub>	1200 V					
V <sub>TM</sub>	1.45 V					
I <sub>GT</sub>	150 mA					
TJ	-40 °C to +125 °C					
Package	TO-247AD 3L					
Circuit configuration	Single SCR					

#### **FEATURES**

- Low IGT parts available
- Designed and qualified according to JEDEC<sup>®</sup> - JESD 47

Pb

- RoHS COMPLIANT HALOGEN FREE
- Flexible solution for reliable AC power rectification
- Easy control peak current at charger power up to reduce passive / electromechanical components
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### APPLICATIONS

• Typical usage is in input rectification crowbar (soft start) and AC switch in motor control, UPS, welding and battery charge

#### DESCRIPTION

The VS-40TPS12.. high voltage series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications.

AEC-Q101 qualified P/N available (VS-40TPS12LHM3, VS-40TPS12ALHM3).

MAJOR RATINGS AND CHARACTERISTICS							
PARAMETER	PARAMETER TEST CONDITIONS VALUES						
I <sub>T(AV)</sub>	Sinusoidal waveform	35	Α				
I <sub>RMS</sub>		55	A				
V <sub>RRM</sub> /V <sub>DRM</sub>		1200	V				
I <sub>TSM</sub>		600	А				
V <sub>T</sub>	40 A, T <sub>J</sub> = 25 °C	1.45	V				
dv/dt		1000	V/µs				
di/dt		100	A/µs				
TJ		-40 to +125	°C				

VOLTAGE RATINGS								
PART NUMBER	V <sub>RRM</sub> /V <sub>DRM</sub> , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> /I <sub>DRM</sub> AT 125 °C mA					
VS-40TPS12AL-M3	1200	1200 1300						
VS-40TPS12L-M3	1200	1300	- 10					



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ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum average on-state current	I <sub>T(AV)</sub>	$T_{C}$ = 79 °C, 180° conduction half sine wave	e	35			
Maximum continuous RMS on-state current as AC switch	I <sub>T(RMS)</sub>		55	А			
Maximum peak, one-cycle	1	10 ms sine pulse, rated V <sub>RRM</sub> applied					
non-repetitive surge current	I <sub>TSM</sub>	10 ms sine pulse, no voltage reapplied	lesiti al	600			
Maximum I <sup>2</sup> t for fusing	l <sup>2</sup> t	10 ms sine pulse, rated V <sub>RRM</sub> applied	Initial $T_{,1} = T_{,1} max.$	1250	A <sup>2</sup> s		
Maximum i-t for fusing	1-1	10 ms sine pulse, no voltage reapplied	ij = ijiliax.	1760			
Maximum I²√t for fusing	l²√t	t = 0.1 ms to 10 ms, no voltage reapplied	17 600	A²√s			
Low level value of threshold voltage	V <sub>T(TO)1</sub>		1.02	V			
High level value of threshold voltage	V <sub>T(TO)2</sub>	T 105 %C	1.23	v			
Low level value of on-state slope resistance	r <sub>t1</sub>	T <sub>J</sub> = 125 °C	9.74				
High level value of on-state slope resistance	r <sub>t2</sub>			7.50	mΩ		
Maximum peak on-state voltage	V <sub>TM</sub>	110 A, T <sub>J</sub> = 25 °C		1.85	V		
Maximum rate of rise of turned-on current	di/dt	T <sub>J</sub> = 25 °C		100	A/µs		
Maximum holding current	l <sub>Η</sub>	Anode supply = 6 V, resistive load, initial $T_J$	= 1 A, I <sub>T</sub> = 25 °C	300			
Maximum latching current	١L	Anode supply = 6 V, resistive load, $T_J = 25$	°C	350			
		$T_J = 25 \text{ °C}$			mA		
Maximum reverse and direct leakage current	I <sub>RRM</sub> /I <sub>DRM</sub>	$T_J = 125 \degree C$ $V_R = rated V_{RRM}/V_{DRM}$		10			
Maximum rate of rise of off-state voltage 40TPS12A	dv/dt	T - T maximum linear to 80 % V - D	500	V/µs			
Maximum rate of rise of off-state voltage 40TPS12	uv/ut	$T_J = T_J$ maximum, linear to 80 % $V_{DRM}$ , $R_g$	1000	v/µs			

TRIGGERING							
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS				
Maximum peak gate power	P <sub>GM</sub>			10	W		
Maximum average gate power	P <sub>G(AV)</sub>			2.5	vv		
Maximum peak gate current	I <sub>GM</sub>			2.5	А		
Maximum peak negative gate voltage	-V <sub>GM</sub>			10	V		
		T <sub>J</sub> = -40 °C		2.0	V		
Maximum required DC gate voltage to trigger	V <sub>GT</sub>	T <sub>J</sub> = 25 °C	Anode supply = 6 V resistive load	1.7			
		T <sub>J</sub> = 125 °C	Tesistive load	1.3			
		T <sub>J</sub> = -40 °C	Anada averative CV(	200	mA		
Maximum required DC gate current to trigger	I <sub>GT</sub>	T <sub>J</sub> = 25 °C	Anode supply = 6 V resistive load	150			
Maximum required DC gate current to trigger		T <sub>J</sub> = 125 °C	Tesistive load	80			
		$T_J = 25 \ ^{\circ}C$ , for 40TPS12A	40				
Maximum DC gate voltage not to trigger for 40TPS12	$V_{GD}$	T 105 °C V retod		0.25	V		
Maximum DC gate current not to trigger for 40TPS12	I <sub>GD</sub>	$T_J = 125 \text{ °C}, V_{DRM} = rated value$		6	mA		
Maximum DC gate voltage not to trigger for 40TPS12A	V <sub>GD</sub>	T 105 °C V roted	0.15	V			
Maximum DC gate current not to trigger for 40TPS12A	I <sub>GD</sub>	T <sub>J</sub> = 125 °C, V <sub>DRM</sub> = rated v	1	mA			

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THERMAL AND MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-40 to +125	°C				
Maximum thermal resistance, junction to case	tion to case R <sub>thJC</sub>		0.6					
Maximum thermal resistance, junction to ambient	R <sub>thJA</sub>	DC operation	40	°C/W				
Maximum thermal resistance, case to heat sink	R <sub>thCS</sub>	Mounting surface, smooth and greased	0.25					
Approximate weight			6	g				
Approximate weight			0.21	oz.				
Mounting torqueminimum	1		6 (5)	kgf · cm				
maximum	1		12 (10)	(lbf · in)				
Marking device		Case style TO-247AD 3L	40TPS12AL					
		Case signe 10-247 AD SL	40TPS12L					

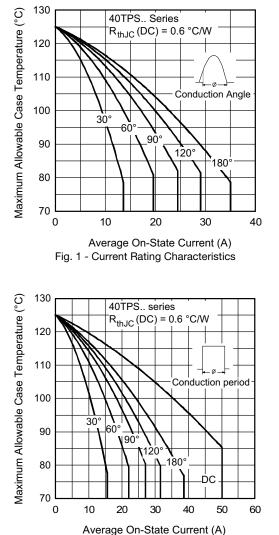
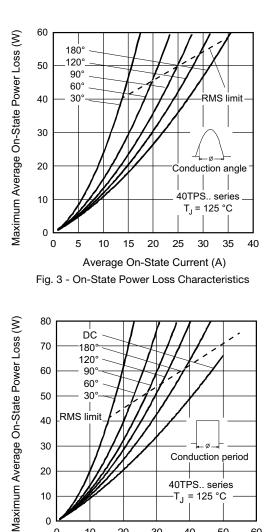


Fig. 2 - Current Rating Characteristics



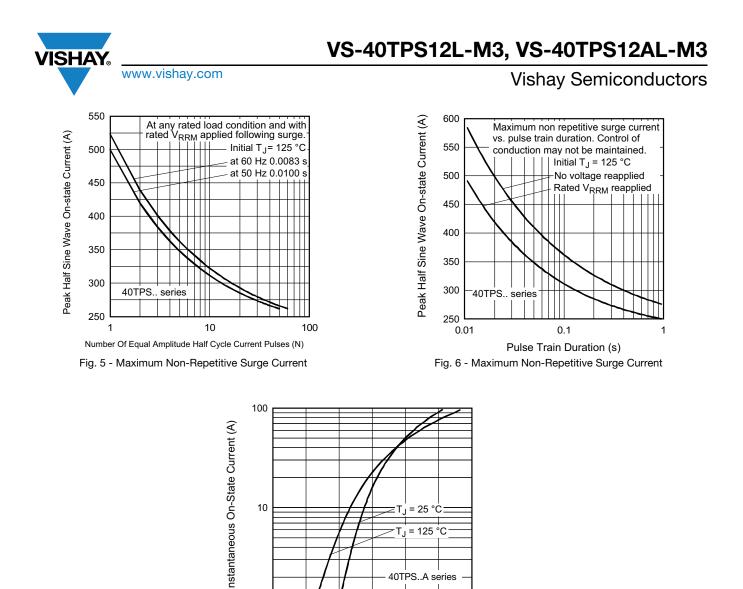
10 20 30 40 50 60 0 Average On-State Current (A)

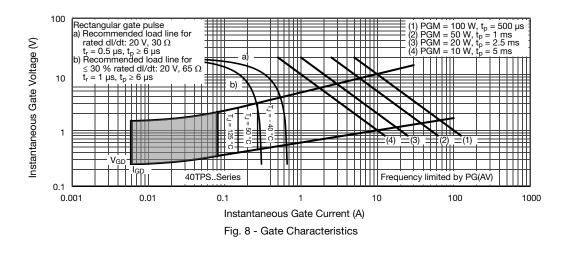
Fig. 4 - On-State Power Loss Characteristics

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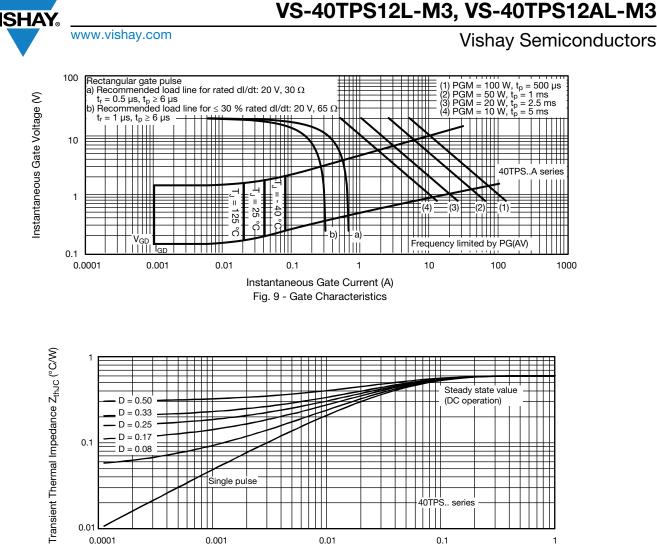
1 0.5 40TPS..A series

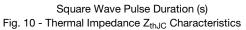
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Instantaneous On-State Voltage (V) Fig. 7 - On-State Voltage Drop Characteristics

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# VS-40TPS12L-M3, VS-40TPS12AL-M3

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### **ORDERING INFORMATION TABLE**

Device code	VS-	40	т	Р	s	12	A	L	-M3
		2	(3)	4	5	6	(7)	(8)	9
	1 -	- Visł	nay Sem	niconduc	ctors pro	duct			
	2 -	Cur	rent rati	ng (40 =	40 A)				
	3 -	Circ	uit confi	iguratior	ו:				
		T =	thyristo	r					
	4 -	Pac	kage:						
		P =	TO-247						
	5 -	Тур	e of silic	con:					
	_				ery rectif	fier	Г		]
	6 -	Volt	age rati	ngs —				12 = 12	200 V
	7 -	• A	= Low I	gt selec	tion 40 ı	mA max	kimum		
		• N	one = s	tandard	Igt seled	ction			
	8 -	L =	long lea	ds					
	9 -	Env	rironmer	ntal digit	:				
		-M3	= halog	gen-free	, RoHS-	complia	int, and	termina	tions le

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-40TPS12AL-M3	25	500	Antistatic plastic tubes					
VS-40TPS12L-M3	25	500	Antistatic plastic tubes					

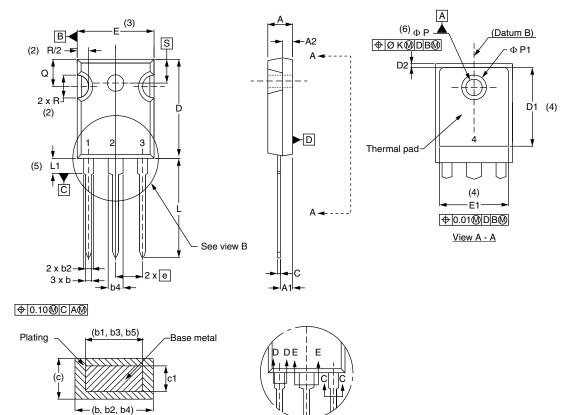
LINKS TO RELATED DOCUMENTS						
Dimensions TO-247AD 3L www.vishay.com/doc?95626						
Part marking information	TO-247AD 3L	www.vishay.com/doc?95007				



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**TO-247AD 3L** 

### **DIMENSIONS** in millimeters and inches



View B

MILLIMETERS INCHES SYMBOL NOTES MIN. MAX. MIN. MAX. 0.209 A 4.65 5.31 0.183 0.087 0.102 A1 2.21 2.59 1.50 2.49 0.059 0.098 A2 b 0.99 1.40 0.039 0.055 b1 0.99 1.35 0.039 0.053 b2 1.65 2.39 0.065 0.094 b3 1.65 2.34 0.065 0.092 b4 2.59 3.43 0.102 0.135 b5 2.59 3.38 0.102 0.133 с 0.38 0.89 0.015 0.035 c1 0.38 0.84 0.015 0.033 D 19.71 20.70 0.776 0.815 3 D1 13.08 -0.515 4

(4) Section C - C, D - D, E - E

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.30	0.020	0.051	
E	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46	BSC	0.215	BSC	
ØК	0.2	0.254		0.010	
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ØР	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51 BSC		0.217	BSC	

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

(3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body

(4) Thermal pad contour optional with dimensions D1 and E1

<sup>(5)</sup> Lead finish uncontrolled in L1

(6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

<sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4

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